

SiC N-Channel MOSFET

FEATURES

- High Blocking Voltage with Low On-Resistance
- High Speed Switching with Low Capacitances
- Increased System Switching Frequency

APPLICATIONS

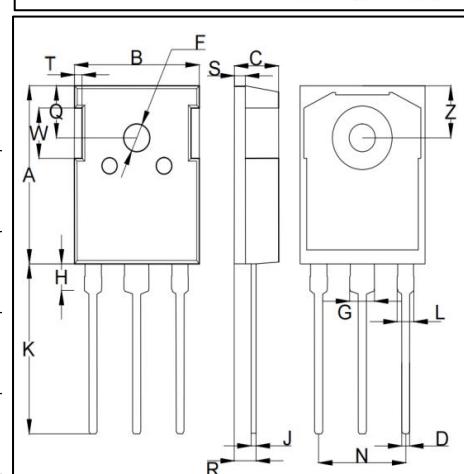
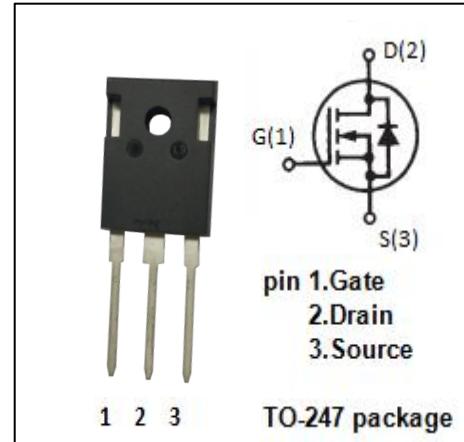
- High Voltage DC/DC Converters
- Automotive EV Battery Charges
- Renewable Energy
- Telecom Power Supplies

Absolute Maximum Ratings($T_C=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	900	V
V_{GSS}	Gate-Source Operation Voltage	-4/+15	V
I_D	Drain Current-Continuous	11.5	A
	Drain Current-Continuous @ $T_C= 100^\circ\text{C}$	7.5	A
I_{DM}	Drain Current-Single Pulse	22	A
P_D	Total Dissipation @ $T_C=25^\circ\text{C}$	54	W
T_J	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	2.3	$^\circ\text{C}/\text{W}$



DIM	mm		
	MIN	TYP.	MAX
A	19.80	20.65	21.50
B	15.40	15.65	15.90
C	4.70	5.00	5.30
D	0.90	1.08	1.26
F	3.50	3.70	3.90
G	2.70	3.00	3.30
H	3.90	4.10	4.30
J	0.50	0.60	0.70
K	19.50	20.00	20.50
L	1.90	2.05	2.20
N	10.80	10.90	11.00
Q	6.00	6.15	6.30
R	2.80	3.00	3.30
S	1.80	2.00	2.20
T	2.15	2.25	2.35
W	4.90	5.00	5.10
Z	6.00	6.15	6.30

SiC N-Channel MOSFET**ELECTRICAL CHARACTERISTICS (T_c=25°C)**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 100uA	900	--	--	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 1.2mA	1.7	--	3.5	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} = 15V, I _D = 7.5A	--	--	364	mΩ
I _{GS}	Gate Source Leakage Current	V _{GS} = -4/+15V, V _{DS} = 0V	--	--	±250	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 900V, V _{GS} = 0V	--	--	100	uA
V _{SD}	Diode Forward Voltage	I _{SD} = 4A, V _{GS} = -4V	--	4.8	--	V

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